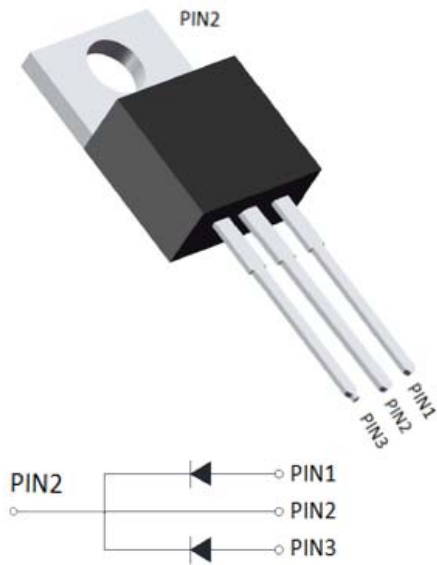


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR2080CT	MBR20100CT	MBR20120CT	MBR20150CT	MBR20200CT
Device marking code			MBR2080CT	MBR20100CT	MBR20120CT	MBR20150CT	MBR20200CT
Repetitive Peak Reverse Voltage	V _{RRM}	V	80	100	120	150	200
Average Rectified Output Current @60Hz sine wave, R-load, T _a =25°C	I _O	A	20				
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	I _{FSM}	A	150				
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	i ² t	A ² s	94				
Storage Temperature	T _{stg}	°C	-55 ~ +150				
Junction Temperature	T _j	°C	-55 ~ +150				

■ Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR2080CT	MBR20100CT	MBR20120CT	MBR20150CT	MBR20200CT
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	I _{FM} =10.0A	0.85		0.9		0.95
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _R RM T _a =25°C	0.1				
	I _{RRM2}		V _{RM} =V _R RM T _a =100°C	20				

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR2080CT	MBR20100CT	MBR20120CT	MBR20150CT	MBR20200CT
Thermal Resistance Between junction and case	R _{θJ-C}	°C/W	2.0				



MBR2080CT THRU MBR20200CT

■ Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR2080CT THRU MBR20200CT	Approximate 1.9	50	1000	5000	Tube

■ Characteristics (Typical)

FIG1:Io -Tc Curve

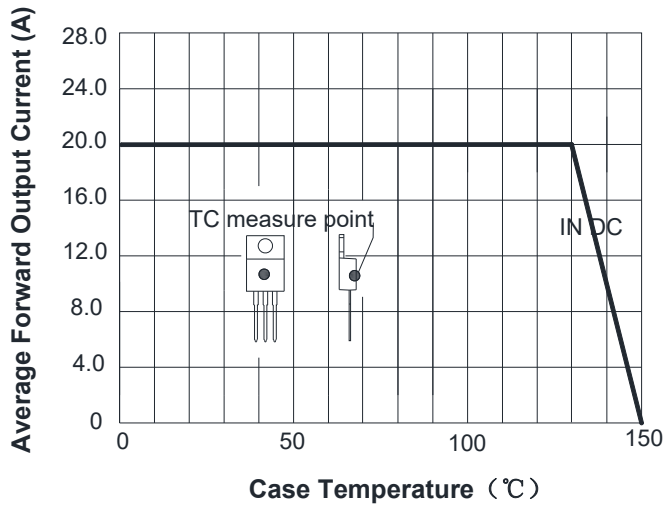


FIG2: Surge Forward Current Capability

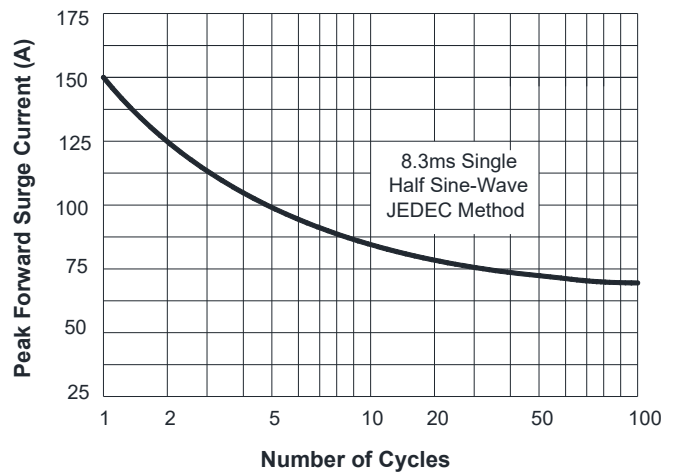


FIG3: Forward Voltage

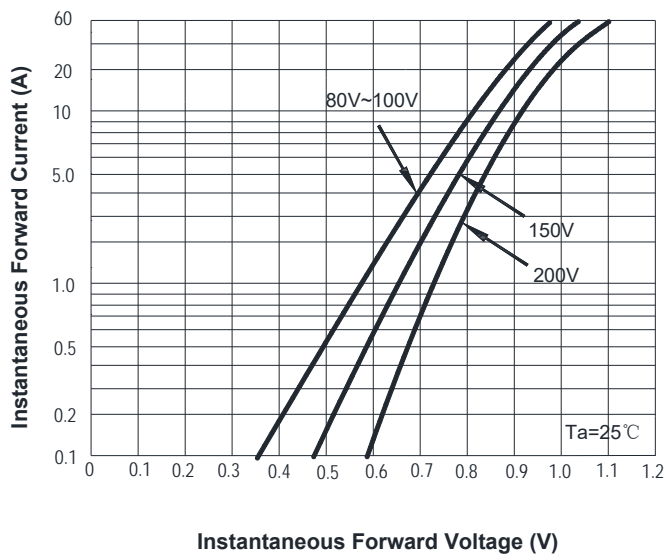
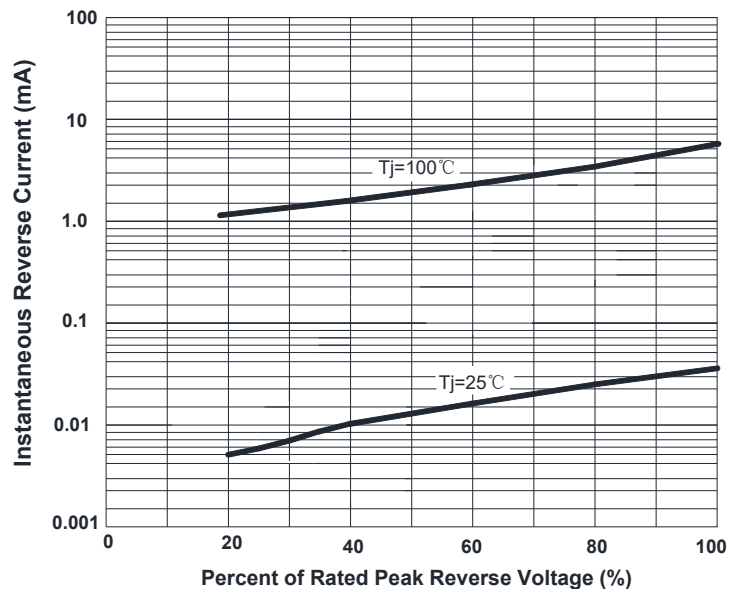


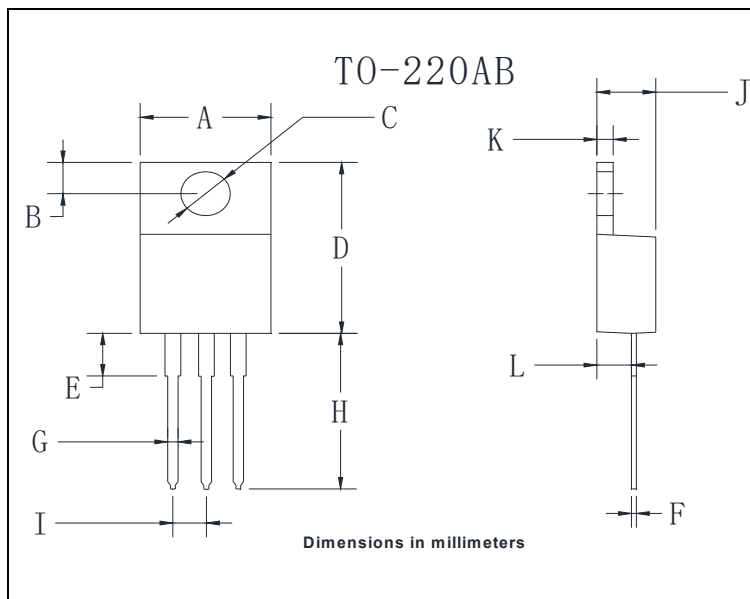
FIG4: Typical Reverse Characteristics





MBR2080CT THRU MBR20200CT

■ Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.5	10.9
B	2.22	3.27
C	3.34	4.31
D	14.5	15.5
E	3.16	4.46
F	0.28	0.64
G	0.68	0.94
H	13.06	14.62
I	2.01	3.07
J	4.04	5.1
K	1.14	1.4
L	2.14	3.19

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